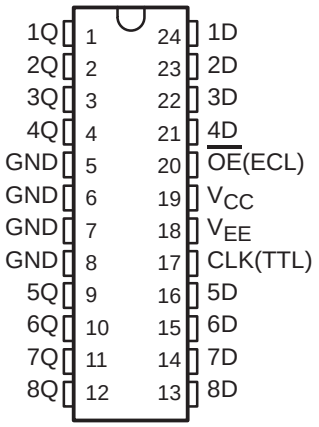
- **10KH Compatible**
- **TTL Clock and ECL Control Inputs**
- **Noninverting Outputs**
- **Flow-Through Architecture Optimizes PCB Layout**
- **Center Pin V_{CC}, V_{EE}, and GND Configurations Minimize High-Speed Switching Noise**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015**
- **Package Options Include Plastic Small-Outline (DW) Package and Standard Plastic (NT) DIPs**

DW OR NT PACKAGE
(TOP VIEW)



description

This octal TTL-to-ECL translator is designed to provide efficient translation between a TTL signal environment and a 10KH ECL signal environment. This device is designed specifically to improve the performance and density of TTL-to-ECL CPU/bus-oriented functions such as memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The eight flip-flops of the ’5578 are edge-triggered D-type flip-flops. On the positive transition of the clock, the Q outputs are set to the logic levels that were set up at the D inputs.

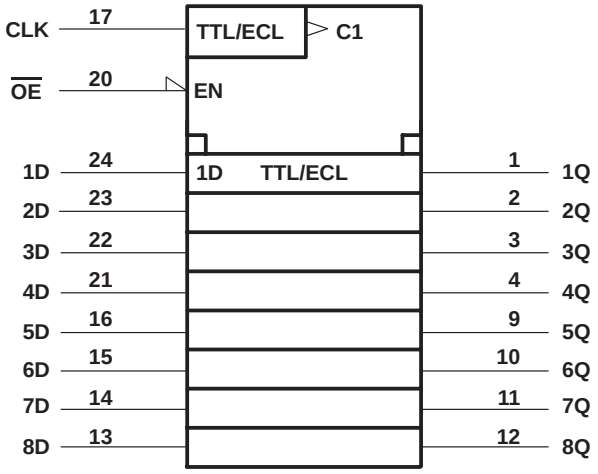
The output-control input $\overline{OE}$ does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while the outputs are off.

The SN10KHT5578 is characterized for operation from 0°C to 75°C.

FUNCTION TABLE

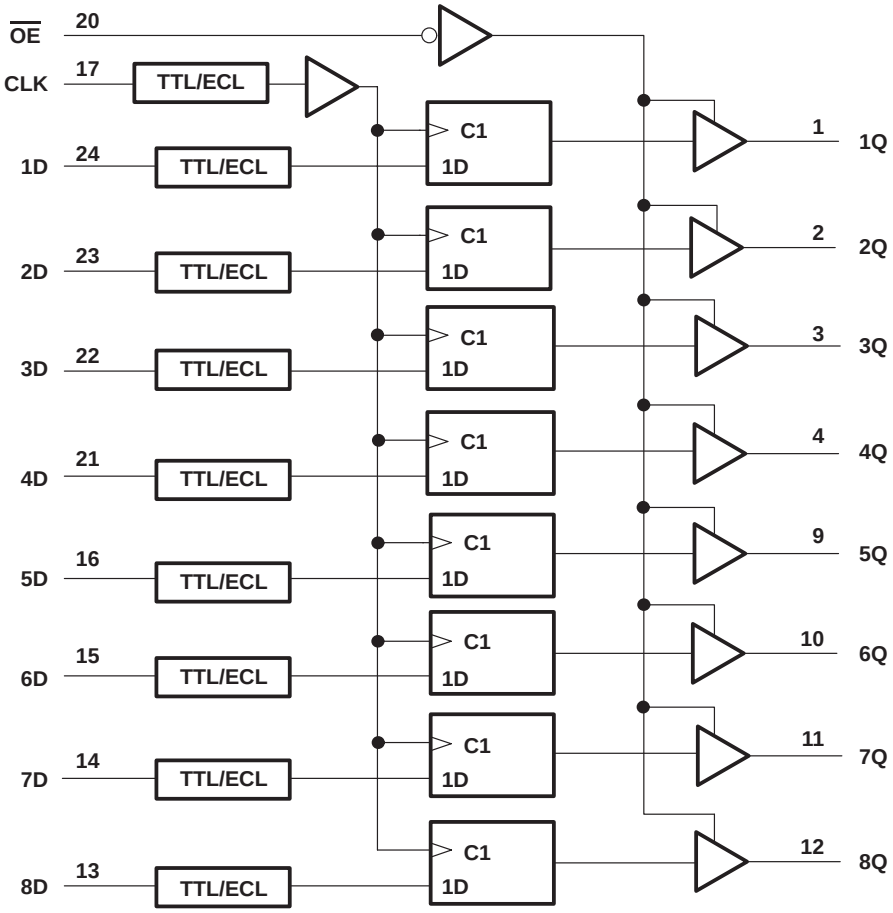
INPUTS			OUTPUT (ECL)
$\overline{OE}$	CLK	D	Q
L	↑	L	L
L	↑	H	H
L	L	X	Q_0
H	X	X	L

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating ambient temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} . . . . . –0.5 V to 7 V
Supply voltage range, V_{EE} . . . . . –8 V to 0 V
Input voltage range (TTL) (see Note 1) . . . . . –1.2 V to 7 V
Input voltage range (ECL) . . . . . V_{EE} to 0 V
Input current range (TTL) . . . . . –30 mA to 5 mA
Current out of any output . . . . . 50 mA
Package thermal impedance, θ_{JA} (see Note 2): DW package . . . . . 81°C/W
NT package . . . . . 67°C/W
Storage temperature range . . . . . –65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The TTL input voltage ratings may be exceeded provided the input current ratings are observed.
2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions

			MIN	NOM	MAX	UNIT
V_{CC}	TTL supply voltage		4.5	5	5.5	V
V_{EE}	ECL supply voltage		–4.94	–5.2	–5.46	V
V_{IH}	TTL high-level input voltage		2			V
V_{IH}	ECL high-level input voltage‡	0°C	–1170		–840	mV
		25°C	–1130		–810	mV
		75°C	–1070		–735	mV
V_{IL}	TTL low-level input voltage				0.8	V
V_{IL}	ECL low-level input voltage‡	0°C	–1950		–1480	mV
		25°C	–1950		–1480	mV
		75°C	–1950		–1450	mV
I_{IK}	TTL input clamp current				–18	mA
T_A	Operating ambient temperature (see Note 3)		0		75	°C

‡ The algebraic convention, in which the least positive (most negative) value is designated minimum, is used in this data sheet for logic levels only.

NOTE 3: Each 10KH-series circuit has been designed to meet the dc specifications shown in the electrical characteristics table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board, and transverse airflow greater than 500 linear ft/min is maintained.

electrical characteristics over recommended operating ambient temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS				MIN	TYP†	MAX	UNIT
V_{IK}	CLK and D inputs	V_{CC} = 4.5 V,	V_{EE} = –4.94 V,	I_I = –18 mA				–1.2	V
I_I	CLK and D inputs	V_{CC} = 5.5 V,	V_{EE} = –5.46 V,	V_I = 7 V				0.1	mA
I_{IH}	CLK and D inputs	V_{CC} = 5.5 V,	V_{EE} = –5.46 V,	V_I = 2.7 V				20	µA
	$\overline{OE}$ input	V_{CC} = 5.5 V,	V_{EE} = –5.46 V,	V_I = –840 mV	0°C			350	
		V_{CC} = 5.5 V,	V_{EE} = –5.46 V,	V_I = –810 mV	25°C			350	
		V_{CC} = 5.5 V,	V_{EE} = –5.46 V,	V_I = –735 mV	75°C			350	
I_{IL}	CLK and D inputs	V_{CC} = 5.5 V,	V_{EE} = –5.46 V,	V_I = 0.5 V				–0.5	mA
	$\overline{OE}$ input	V_{CC} = 5.5 V,	V_{EE} = –5.46 V,	V_I = –1950 mV	0°C	0.5			µA
					25°C	0.5			
					75°C	0.5			
V_{OH}‡		V_{CC} = 4.5 V,	V_{EE} = –5.2 V ± 5%,	See Note 4	0°C	–1020		–840	mV
					25°C	–980		–810	
					75°C	–920		–735	
V_{OL}‡		V_{CC} = 4.5 V,	V_{EE} = –5.2 V ± 5%,	See Note 4	0°C	–1950		–1630	mV
					25°C	–1950		–1630	
					75°C	–1950		–1600	
I_{CCH}		V_{CC} = 5.5 V,	V_{EE} = –5.46 V				17.5	25	mA
I_{CCL}		V_{CC} = 5.5 V,	V_{EE} = –5.46 V				15	22	mA
I_{EE}		V_{CC} = 5.5 V,	V_{EE} = –5.46 V				–104	–149	mA
C_i		V_{CC} = 5 V,	V_{EE} = –5.2 V,	f = 10 MHz			4		pF

† All typical values are at V_{CC} = 5 V, V_{EE} = –5.2 V, T_A = 25°C.
‡ The algebraic convention, in which the least positive (most negative) value is designated minimum, is used in this data sheet for logic levels only.
NOTE 4: Outputs are terminated through a 50-Ω resistor to –2 V.

timing requirements over recommended operating conditions

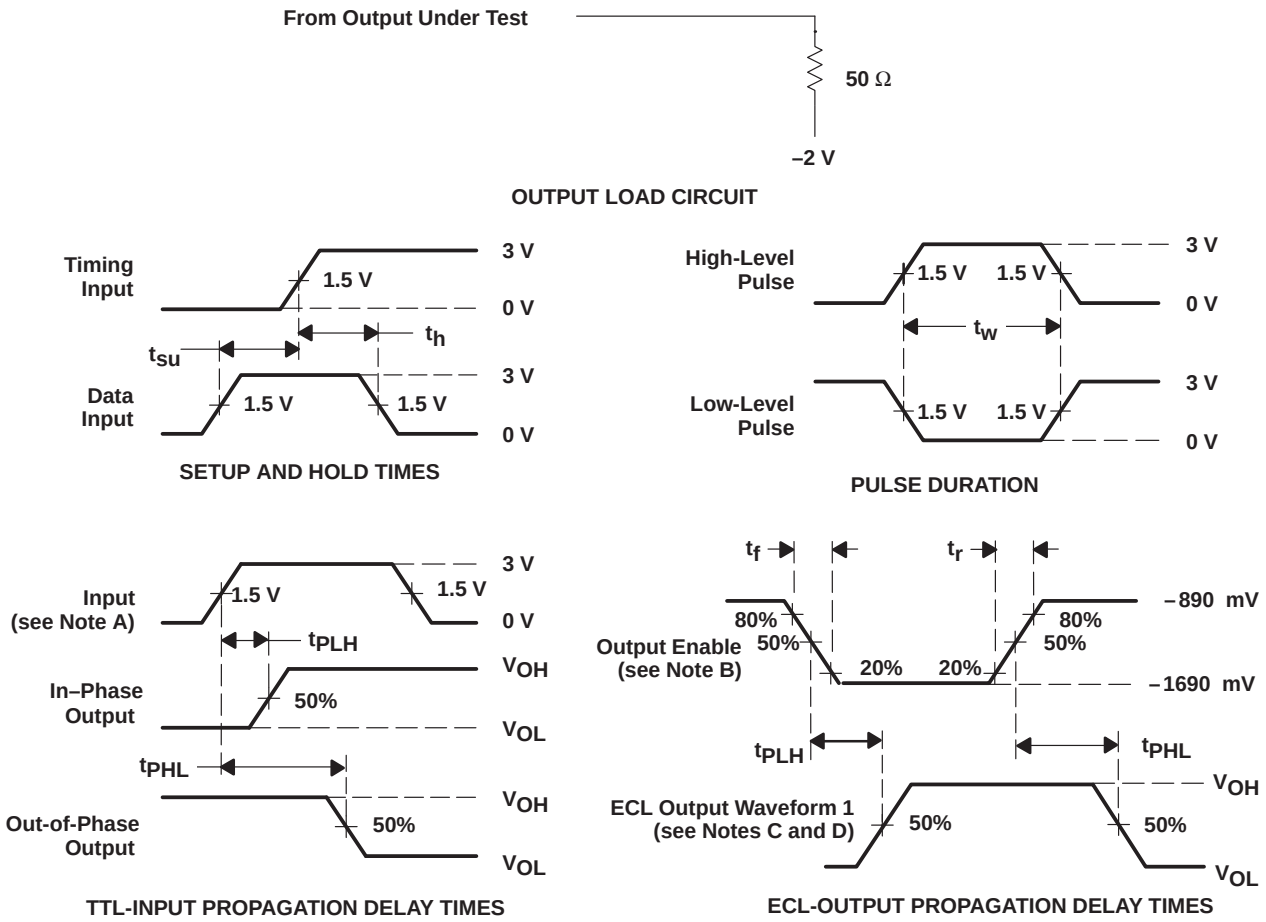
			MIN	MAX	UNIT
f_{clock}	Clock frequency			180	MHz
t_w	Pulse duration, CLK	High	4		ns
		Low	4		
t_{su}	Setup time, data before CLK↑	High	1.5		ns
		Low	2.5		
t_h	Hold time, data after CLK↑	High	1		ns
		Low	1		

switching characteristics over recommended ranges of supply voltage and operating ambient temperature (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	TYP†	MAX	UNIT
f_{max}			180			MHz
t_{PLH}	CLK	Q	0.8	2.2	4	ns
t_{PHL}			0.8	2.1	3.8	
t_{PLH}	OE	Q	0.5	1.4	3.2	ns
t_{PHL}			0.5	1.7	3.3	
t_r		Y		1.5		ns
t_f		Y		1.5		ns

† All typical values are at V_{CC} = 5 V, V_{EE} = –5.2 V, T_A = 25°C.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. For TTL inputs, input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r = 2.5 ns, t_f = 2.5 ns.
B. For ECL inputs, input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r = 1.5 ns, t_f = 1.5 ns.
C. Waveform 1 is for an output with internal conditions such that the output is high except when disabled by $\overline{OE}$.
D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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